2SD1478, 2SD1478A

Silicon NPN epitaxial planar type darlington

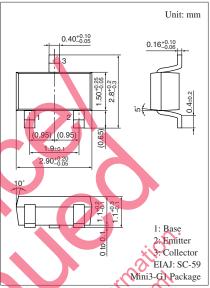
For low-frequency amplification

■ Features

- Forward current transfer ratio h_{FE} is designed high, which is appropriate to the driver circuit of motors and printer hammer
- A shunt resistor is omitted from the driver.

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SD1478	V _{CBO}	30	V
(Emitter open)	2SD1478A		60	- 4
Collector-emitter voltage	2SD1478	V _{CEO}	25	V
(Base open)	2SD1478A		50	
Emitter-base voltage (Coll	V _{EBO}	5	V	
Collector current	I_{C}	500	mA	
Peak collector current	I _{CP}	750	mA	
Collector power dissipation	P _C	200	mW	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +1 5 0	°C	

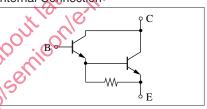


Marking Symbol: 5

• 2SD1478: 2N

• 2SD1478A.2O

Internal Connection



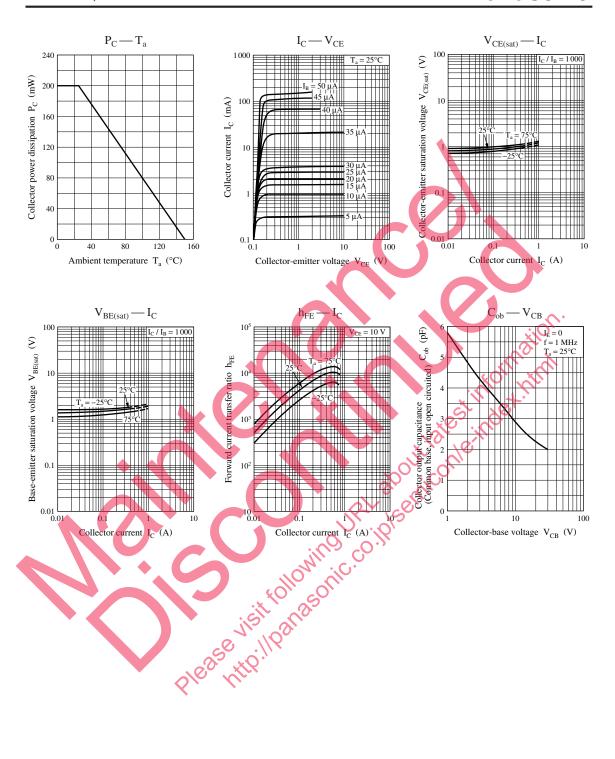
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

Parameter	Syr	mbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage 2	2SD1478 V	СВО	$I_{\rm C} = 100 \mu{\rm A}, I_{\rm E} = 0$	30			V
(Emitter open)	2SD1478A		£60, 80,	60			
Collector-emitter voltage 2	2SD1478 V	CEO	$I_C = 1$ mA, $I_B = 0$	25			V
(Base open)	2SD1478A	7	1100	50			
Emitter-base voltage (Collecto	or open)	EBO _	$I_E = 100 \mu A, I_C = 0$	5			V
Collector-base cutoff current (Emi	itter open I	СВО	$V_{CB} = 25 \text{ V}, I_{E} = 0$			100	nA
Emitter-base cutoff current (Collec	ctor open) I _I	EBO	$V_{EB} = 4 V, I_C = 0$			100	nA
Forward current transfer ratio	*1, 2	h _{FE}	$V_{CE} = 10 \text{ V}, I_{C} = 500 \text{ mA}$	4000		20 000	_
Collector-emitter saturation vo	oltage *1 V _C	CE(sat)	$I_C = 500 \text{ mA}, I_B = 0.5 \text{ mA}$			2.5	V
Base-emitter saturation voltag	ge *1 V _B	BE(sat)	$I_C = 500 \text{ mA}, I_B = 0.5 \text{ mA}$			3.0	V
Transition frequency		f_T	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz

 $Note) \ 1. \ Measuring \ methods \ are \ based \ on \ JAPANESE \ INDUSTRIAL \ STANDARD \ JIS \ C \ 7030 \ measuring \ methods \ for \ transistors.$

- 2. *1: Pulse measurement
 - *2: Rank classification

Rank	Q	R		
h_{FE}	4000 to 10000	8 000 to 20 000		



2 SJC00224CED

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